NSN 5962-01-226-4349

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Body	Length:
0.840	inches
Body	Width:
Betwe	en 0.220 inches and 0.310 inches
Body	Height:
0.185	inches
Maxim	num Power Dissipation Rating:
794.0	milliwatts
Opera	ting Tempurature Range:
-55.0/+	-125.0 degrees celsius
Storag	ge Tempurature Range:
-65.0/+	-150.0 degrees celsius
End A	pplication:
An/bps	s14to15e
Featu	res Provided:
Herme	tically sealed and burn in and programmable and bipolar and schottky
Inclos	ure Material:
Ceram	ic
Inclos	ure Configuration:
Dual-ir	n-line
Outpu	t Logic Form:
Transi	stor-transistor logic
Input	Circuit Pattern:
10 inp	ut
Case	Outline Source And Designator:
D-2 mi	il-m-38510
Termi	nal Surface Treatment:
Solder	
Voltag	e Rating And Type Per Characteristic:
-0.5 vc	olts power source and 7.0 volts power source
Time I	Rating Per Chacteristic:
85.00	nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memo	ry Device Type:
Prom	
Memo	ry Capacity:
Unkno	wn
Test D	Pata Document:
96906	-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Termi	nal Type And Quantity:
16 prir	nted circuit
Shelf	Life:
N/a	

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

